



## UTR2113

Advance

LINEAR INTEGRATED CIRCUIT

### HIGH AND LOW SIDE DRIVER

#### DESCRIPTION

The **UTR2113** are high voltage, high speed power MOSFET and IGBT drivers with independent high-side and low-side referenced output channels. Pro-prietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. Logic in-puts are compatible with standard CMOS or LSTTL out-put, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side configuration which operates up to 500V or 600V.

#### FEATURES

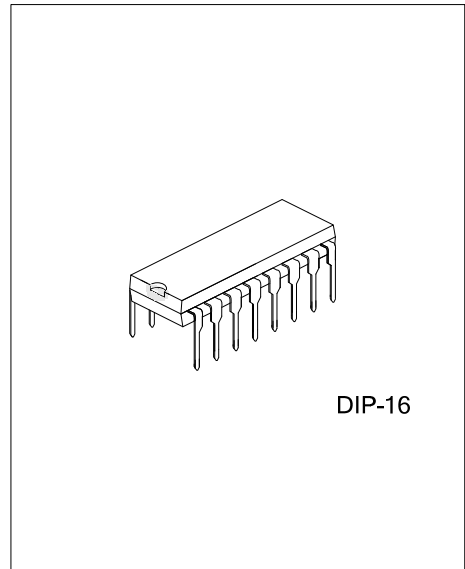
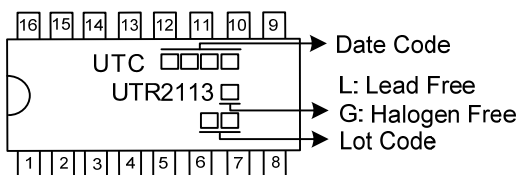
- \* Floating channel designed for bootstrap operation
- \* Fully operational to 500V or 600V
- \* Tolerant to negative transient voltage, dV/dt immune
- \* Gate drive supply range from 10V to 20V
- \* Undervoltage lockout for both channels
- \* 3.3V logic compatible
- \* Separate logic supply range from 3.3V to 20V
- \* Logic and power ground  $\pm 5V$  offset
- \* CMOS Schmitt-triggered inputs with pull-down
- \* Cycle by cycle edge-triggered shutdown logic
- \* Matched propagation delay for both channels
- \* Outputs in phase with inputs

#### ORDERING INFORMATION

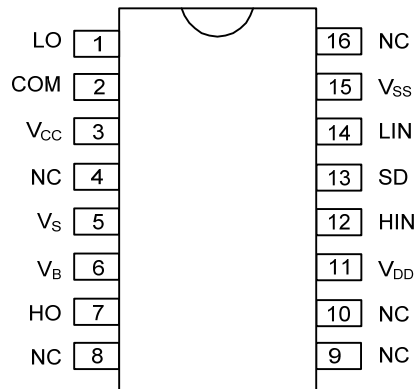
Ordering Number		Package	Packing
Lead Free	Halogen Free		
UTR2113L-D16-T	UTR2113G-D16-T	DIP-16	Tube

<p>UTR2113G-D16-T</p> <ul style="list-style-type: none"> <li>(1) Packing Type</li> <li>(2) Package Type</li> <li>(3) Green Package</li> </ul>	<ul style="list-style-type: none"> <li>(1) T: Tube</li> <li>(2) D16: DIP-16</li> <li>(3) G: Halogen Free and Lead Free, L: Lead Free</li> </ul>
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#### MARKING



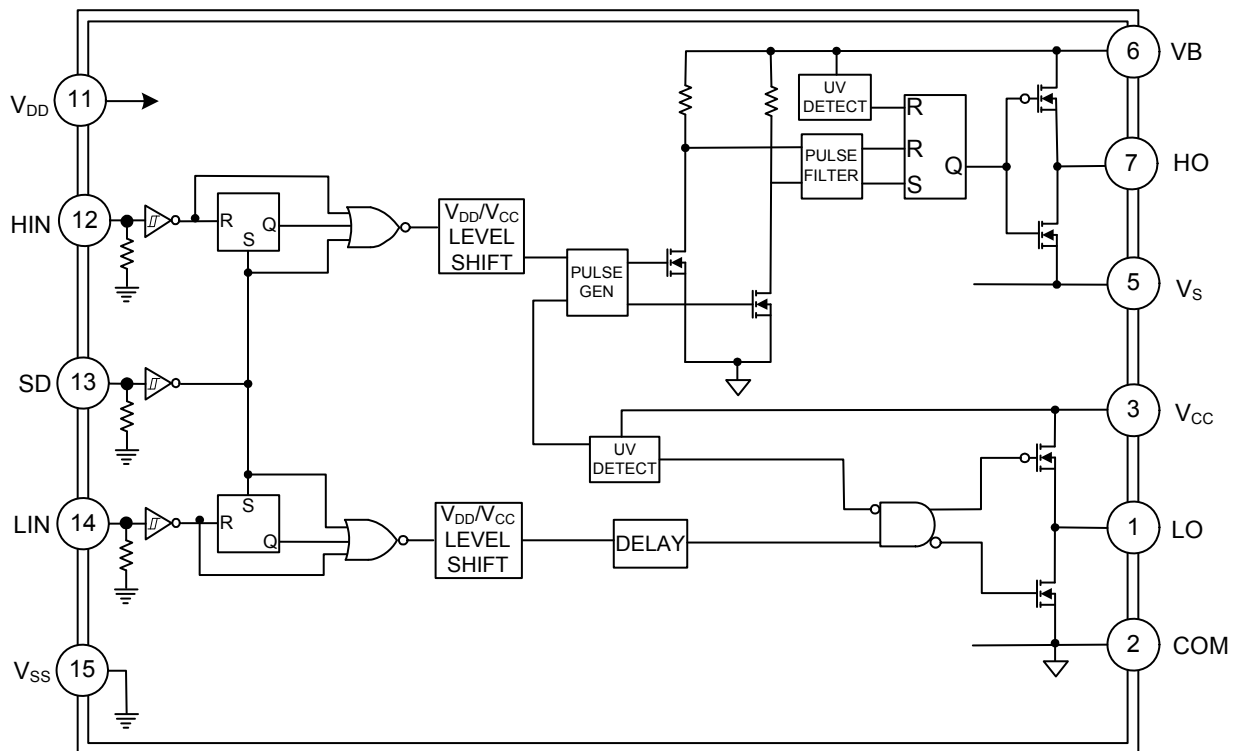
■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	LO	Low-side gate drive output
2	COM	Low-side return
3	V <sub>CC</sub>	Low-side supply
4, 8~10, 16	NC	
5	V <sub>S</sub>	High-side floating supply return
6	V <sub>B</sub>	High-side floating supply
7	HO	High-side gate drive output
11	V <sub>DD</sub>	Logic supply
12	HIN	Logic input for high-side gate driver output (HO), in phase
13	SD	Logic input for shutdown
14	LIN	Logic input for low-side gate driver output (LO), in phase
15	V <sub>SS</sub>	Logic ground

■ BLOCK DIAGRAM



### ■ ABSOLUTE MAXIMUM RATING (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
High-Side Floating Absolute Voltage	V <sub>B</sub>	620 (Note 3)	V
High-Side Floating Supply Offset Voltage	V <sub>S</sub>	V <sub>B</sub> +0.3	V
High-Side Floating Output Voltage	V <sub>HO</sub>	V <sub>B</sub> +0.3	V
Low-Side and logic Fixed Supply Voltage	V <sub>CC</sub>	20 (Note 3)	V
Low-Side Output Voltage	V <sub>LO</sub>	V <sub>CC</sub> +0.3	V
Logic Supply Voltage	V <sub>DD</sub>	V <sub>SS</sub> +20 (Note 3)	V
Logic Supply Offset Voltage	V <sub>SS</sub>	V <sub>CC</sub>	V
Logic Input Voltage (HIN & LIN)	V <sub>IN</sub>	V <sub>DD</sub>	V
Allowable Offset Supply Voltage Transient	dVs/dt	50	V
Power Dissipation	P <sub>D</sub>	1.25	W
Maximum Junction Temperature	T <sub>J</sub>	+150	°C
Maximum Storage Temperature Range	T <sub>STG</sub>	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

3. All supplies are fully tested at 25V, and an internal 20V clamp exists for each supply.

### ■ RECOMMENDED OPERATING RATINGS

(For proper operation, the device should be used within the recommended conditions. The V<sub>S</sub> and V<sub>SS</sub> offset ratings are tested with all supplies biased at a 15V differential.)

PARAMETER	SYMBOL	RATINGS	UNIT
High-Side Floating Supply Absolute Voltage	V <sub>B</sub>	V <sub>S</sub> +10 ~ V <sub>S</sub> +20	V
High-Side Floating Supply Offset Voltage	V <sub>S</sub>	600 (Note 1)	V
High-Side Floating Output Voltage	V <sub>HO</sub>	V <sub>S</sub> ~ V <sub>B</sub>	V
Low-Side Fixed Supply Voltage	V <sub>CC</sub>	10 ~ 20	V
Low-Side Output Voltage	V <sub>LO</sub>	0 ~ V <sub>CC</sub>	V
Logic Supply Voltage	V <sub>DD</sub>	V <sub>SS</sub> +3 ~ V <sub>SS</sub> +20	V
Logic Supply Offset Voltage	V <sub>SS</sub>	-5 ~ 5 (Note 2)	V
Logic Input Voltage (HIN, LIN & SD)	V <sub>IN</sub>	V <sub>SS</sub> ~ V <sub>DD</sub>	V
Ambient Temperature	T <sub>A</sub>	-40 ~ +125	°C

Notes: 1. Logic operational for V<sub>S</sub> of -4V to +500V. Logic state held for V<sub>S</sub> of -4 V to -V<sub>BS</sub>.

2. When V<sub>DD</sub> < 5 V, the minimum V<sub>SS</sub> offset is limited to -V<sub>DD</sub>.

### ■ THERMAL DATA

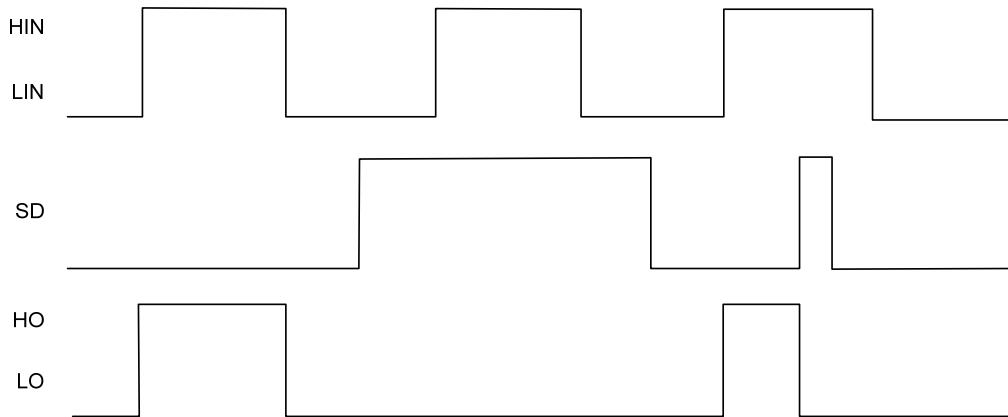
PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ <sub>JA</sub>	100	°C/W

### ■ ELECTRICAL CHARACTERISTICS

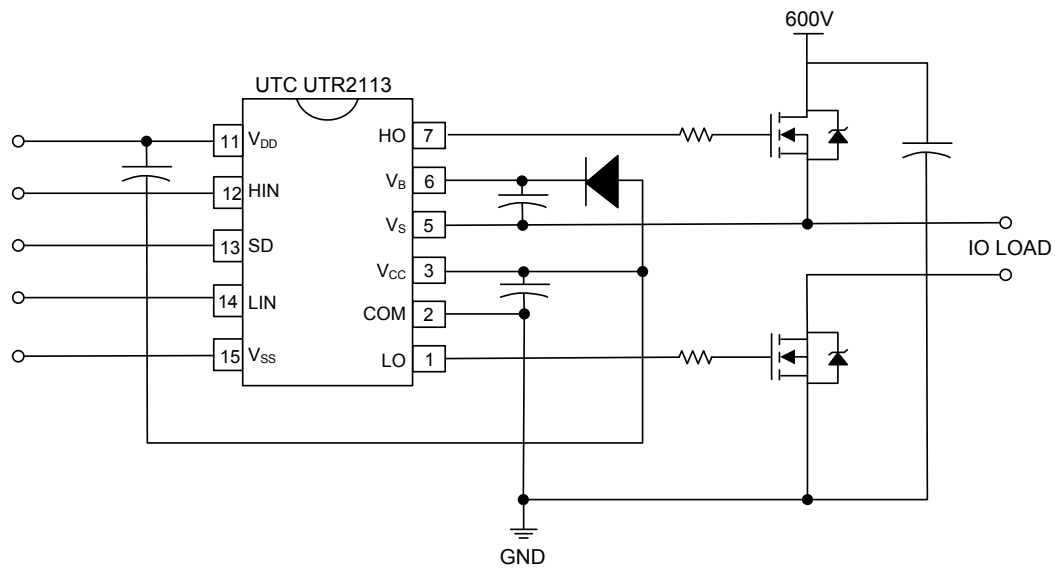
[ $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ,  $V_{DD}$ )=15V,  $C_L$ =1000pF,  $V_{SS}$ =COM and  $T_A$ =25°C unless otherwise specified. The  $V_{IN}$ ,  $V_{TH}$ , and  $I_{IN}$  parameters are referenced to  $V_{SS}$  and are applicable to all three logic input leads: HIN, LIN, and SD. The  $V_O$  and  $I_O$  parameters are referenced to COM and are applicable to the respective output leads: HO or LO.]

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Turn-ON Propagation Delay	$t_{on}$	$V_S=0V$		180	250	ns
Turn-OFF Propagation Delay	$t_{OFF}$	$V_S=600V$		120	150	ns
Shutdown Propagation Delay	$t_{SD}$			130	160	ns
Turn-ON Rise Time	$t_r$			25	35	ns
Turn-OFF Fall Time	$t_f$			17	25	ns
Turn-ON/OFF	MT				20	ns
Logic "1" Input Voltage	$V_{IH}$		10			V
Logic "0" Input Voltage	$V_{IL}$				5.5	V
High level Output Voltage, $V_{BIAS} - V_O$	$V_{OH}$	$I_O=0A$			1.5	V
Low Level Output Voltage, $V_O$	$V_{OL}$	$I_O=20mA$			0.15	V
Offset Supply Leakage Current	$I_{LK}$	$V_B=V_S=600V$			50	$\mu A$
Quiescent $V_{BS}$ Supply Current	$I_{QBS}$	$V_{IN}=0V \sim V_{DD}$		125	230	$\mu A$
Quiescent $V_{CC}$ Supply Current	$I_{QCC}$			180	340	$\mu A$
Quiescent $V_{DD}$ Supply Current	$I_{QDD}$			15	30	$\mu A$
Logic "1" Input Bias Current	$I_{IN+}$	$V_{IN}=V_{DD}$		20	40	$\mu A$
Logic "0" Input Bias Current	$I_{IN-}$	$V_{IN}=0V$			5.0	$\mu A$
$V_{BS}$ supply undervoltage positive going threshold	$V_{BSUV+}$		7.5	8.6	9.7	V
$V_{BS}$ Supply Undervoltage Negative Going Threshold	$V_{BSUV-}$		7.0	8.2	9.4	V
$V_{CC}$ Supply Undervoltage Positive Going Threshold	$V_{CCUV+}$		7.4	8.5	9.6	V
$V_{CC}$ Supply Undervoltage Negative Going Threshold	$V_{CCUV-}$		7.0	8.2	9.4	V
Output High Short Circuit Pulsed Current	$I_{O+}$	$V_{IN}=V_{DD}$ , $V_O=0V$ , $P_W \leq 10\mu s$	2.0	2.5		A
Output Low Short Circuit Pulsed Current	$I_{O-}$	$V_{IN}=0V$ , $V_O=15V$ , $P_W \leq 15\mu s$	2.0	2.5		A

■ TIMING DIAGRAM



■ TYPICAL APPLICATION CIRCUIT



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